# **AN5817NK**

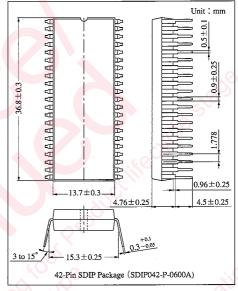
# Multiplex Sound Demodulator IC for TV in the U.S.A.

### Overview

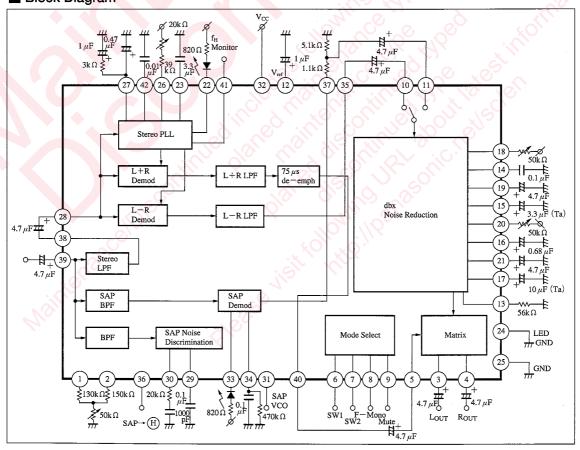
The AN5817NK is a TV multiplex sound signal processor IC for TV in the U.S.A. It includes all multiplex sound demodulator functions needed for U.S.A. TV standard.

#### Features

- Single chip IC of TV multiplex sound demodulator for the USA standard (combined Zenith with dbx method)
- Only 4 adjustment points (two separation adjustments, one filter adjustment, and one VCO adjustment)
- $\bullet$  Supply voltage:  $9\pm1V$



### Block Diagram



### ■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	Vcc	11.0	V
Supply current	I <sub>cc</sub>	50	mA
Power dissipation Note 2)	P <sub>D</sub>	760	mW
LED driving current Note 3)	$I_{LED}$	20	mA
Operating ambient temperature Note 1)	Topr	-20  to  +75	ొ
Storage temperature Note 1)	$T_{stg}$	-55 to $+150$	r

Note 1) Ta=25 $^{\circ}$ C except operating ambient temperature and storage temperature.

Note 2) Allowable power dissipation of the package at Ta=70°C. Note 3) Flow-in currents to Pin②, ③

# ■ Recommended Operating Range $(Ta=25^{\circ}C)$

Parameter	Symbol	Range
Operating supply voltage range	V <sub>cc</sub>	8.0V to 10.0V

# ■ Electrical Characteristics $(V_{CC}=9V, Ta=25\pm2^{\circ}C)$

Parameter	Symbol	Condition	min	typ	max	Unit
Total circuit current	$I_{CC}$	No signal	22	30	38	mA
Monaural output level	V <sub>0 (Mon)</sub>	f=1kHz (Mono.) 100%mod.	450	500	550	mVrms
Monaural frequency characteristics – 1	V <sub>1 (Mon)</sub>	f=300Hz (Mono.) 30%mod.	-0.5	0	+0.5	dB
Monaural frequency characteristics -2	V <sub>2 (Mon)</sub>	f=8kHz (Mono.) 30%mod.	-1.7	-1.0	+0.3	dB
Monaural distortion rate	THD <sub>(Mon)</sub>	f=1kHz (Mono.) 100%mod.	_		0.7	%
Monaural noise level	Vn <sub>(Mon)</sub>	Input short BPF (A curve)	_	_	-65	dBV
(L), (R) output voltage difference	V <sub>LR (Mon)</sub>	f=300Hz (Mono.) 100%mod.	-0.5	0	+0.5	dB
Stereo output level	V <sub>0 (st)</sub>	f=1kHz (L(R)-only) 100%mod.	400	500	600	mVrms
Stereo frequency characteristics – 1	V <sub>1 (st)</sub>	f=300Hz (L(R)-only) 30%mod.	-0.7	0	+0.7	dB
Stereo frequency characteristics -2	V <sub>2 (st)</sub>	f=3kHz (L(R)-only) 30% mod.	-1.0	0	+1.0	dB
Stereo frequency characteristics – 3	V <sub>3 (st)</sub>	f=8kHz (L(R)-only) 30% mod.	-2.0	-1.0	0	dB
Stereo distortion rate	THD <sub>(st)</sub>	f=1kHz (L(R)-only) 100%mod.	_		1.0	%
Stereo noise level	Vn <sub>(st)</sub>	$f = 15.73 \text{kHz } (f_{\text{H}})$ $v = 0.084 V_{\text{P-P}}, \text{BPF}$			-65	dBV
Stereo discrimination level	V <sub>TH (st)</sub>	f=15.73kHz (f <sub>H</sub> )	10	15	22	mVrms
Stereo discrimination hysteresis	V <sub>HY</sub> (st)	f=15.73kHz (f <sub>H</sub> )	-10		-3	dB
SAP output level	V <sub>0 (SAP)</sub>	f=1kHz (SAP) 100%mod.	400	500	600	mVrms
SAP frequency characteristics – 1	V <sub>1 (SAP)</sub>	f=300Hz (SAP) 30%mod.	-1.0	0	+1.5	dB
SAP frequency characteristics -2	V <sub>2 (SAP)</sub>	f=3kHz (SAP) 30%mod.	-1.5	0	+1.0	dB
SAP distortion rate	THD <sub>(SAP)</sub>	f=1kHz (SAP) 100%			1.5	%

 $\label{eq:local_potential} \mbox{\% Input level (at 100\% modulation) $L+R: 0.424V_{P-P}, L-R: 0.848V_{P-P}, pilot: 0.084V_{P-P}, SAP: 0.254V_{P-P}, C-R: 0.848V_{P-P}, D-R: 0.848V_{P-P$ 

# 

Parameter	Symbol	Condition	min	typ	max	Unit
SAP noise level	$V_{n \text{ (SAP)}}$	$f = 78.7 \text{kHz} (5f_{\text{H}})$ $v = 0.42 \text{V}_{\text{P-P}}, \text{BPF}$			-75	dBV
SAP discrimination level	V <sub>TH</sub> (SAP)	$f = 78.7 \text{kHz} (5 f_{\text{H}})$	20	_	60	mVrms
SAP discrimination hysteresis	V <sub>HY</sub> (SAP)	$f = 78.7 \text{kHz} (5 f_{\text{H}})$	-4.0		-1.0	dB
SAP—OUT output level .	V <sub>0 (SAPO)</sub>	f=1kHz (SAP, dbx-off) 100%mod.	400	500	600	mVrms
SAP-OUT frequency characteristics -1	V <sub>1 (SAPO)</sub>	f=300Hz (SAP, dbx-off) 30%mod.	-0.5	0	+0.5	dB
SAP-OUT frequency characteristics-2	V <sub>2 (SAPO)</sub>	f=3kHz (SAP, dbx-off) 30% mod.	-0.5	0	+0.5	dB
SAP-OUT distortion rate	THD <sub>(SAPO)</sub>	f=1kHz (SAP, dbx-off) 100%mod.			2.0	%
SAP-OUT noise level	V <sub>n (SAPO)</sub>	$f=78.7 \text{kHz} (5f_{\text{H}})$ $v=0.42 \text{V}_{\text{P-P}}, \text{BPF}$			-46	dBV
SAP→Stereo crosstalk	CT <sub>1</sub>	(SAP) 1kHz, 100%mod. (Stereo) pilot—signal	_		-50	dB
Stereo→SAP crosstalk	CT <sub>2</sub>	(Stereo) 1kHz, 100%mod. (SAP) carrier—signal	_		-50	dB
Mute	Mute	(Mon) 1kHz, 100% mod.			-56	dB
Stereo separation (30%) -1	Sep <sub>30-1</sub>	f=300Hz L(R) -only 30%mod.	(25)			dB
Stereo separation (30%) −2	Sep <sub>30-2</sub>	f=1kHz L(R) -only 30%mod.	(25)	_		dB
Stereo separation (30%) -3	Sep <sub>30-3</sub>	f=3kHz L(R) -only 30%mod.	(25)			dB
Stereo separation (30%) -4	Sep <sub>30-4</sub>	f=8kHz L (R) -only 30%mod.	(20)	_		dB
Stereo separation (100%) -1	Sep <sub>100-1</sub>	f=300Hz L(R) -only 100%mod.	(25)			dB
Stereo separation (100%) -2	Sep <sub>100-2</sub>	f=1kHz L(R) -only 100% mod.	(20)	_		dB
Stereo separation (100%) -3	Sep <sub>100-3</sub>	f=3kHz L(R) -only 100% mod.	(25)			dB
Stereo separation (100%) -4	Sep <sub>100-4</sub>	f=8kHz L(R) -only 100% mod.	(15)	_		dB
Stereo separation (10%) -1	Sep <sub>I0-I</sub>	f=300Hz L(R) -only 10%mod.	(25)			dB
Stereo separation (10%) -2	Sep <sub>10-2</sub>	f=1kHz L(R) -only 10%mod.	(20)			dB
Stereo separation (10%) -3	Sep <sub>10-3</sub>	f=3kHz L(R) -only 10%mod.	(25)			dB
Stereo separation (10%) -4	Sep <sub>10-4</sub>	f=8kHz L(R) -only 10%mod.	(20)			dB
SAP→Mono crosstalk	CT <sub>3</sub>	(SAP) 1kHz 100%mod. (Mono) 1kHz 0%mod.		(-53)		dB
Mono→SAP crosstalk	$\mathrm{CT}_4$	(SAP) 1kHz 0%mod. (Mono) 1kHz 100%mod.	_	(-60)	(-56)	dB

Note) The characteristics value in parentheses is not a guaranteed value, but reference one on design.

# ■ Pin Descriptions

Pin No.	Pin name	Pin voltage (V <sub>CC</sub> =9V)	Equivalent circuit	Description
1	dbx filter adjustment	1.2V	V <sub>cc</sub>	Adjustment of dbx filter control current
2	SAP0/stereo filter adj.	1.2V	V <sub>cc</sub>	Adjustment of SAP/stereo filter control current
3	L output	4.7V	3 GND	(L) Line-Out output
4	R output	4.7V	V <sub>cc</sub>	(R) Line-Out output
5	Matrix (L+R) input	4.7V	V <sub>cc</sub> S  GND	Matrix Circuit (L+R) signal input
6	SAP mode change-over	ov	V <sub>CC</sub> 1.9V 9kΩ GND	Under the SAP output condition,  Lout Rout  H (L+R) (SAP) more than 2.5V  L (SAP) (SAP) less than 0.8V

Pin No.	Pin name	Pin voltage (V <sub>CC</sub> =9V)	Equivalent circuit	Description
7	Stereo/SAP change-over	0V	7 9kΩ 1.9V GND	H: Stereo output mode, more than 2.5V L: SAP output mode, up to 0.8V
8	Forced monaural switching	0V	$8$ $9k\Omega$ $68k\Omega$ $9k\Omega$ $9k\Omega$ $9k\Omega$ $9k\Omega$ $9k\Omega$	H: (more than 4.2V) Stereo output mode M: (2.2V to 3.2V) Forced monaural mode LED off L: (Up to 0.8V) Forced monaural mode LED on
9	Mute switching	0V	9 9kΩ 1.9V 68kΩ GND	H: Mute mode Output mute, more than 2.5V LED off
10	L−R dbx input	4.7V	V <sub>cc</sub> V <sub>cc</sub> GND	dbx NR input for L-R signal
11	SAP dbx input	4.7V	V <sub>cc</sub> V <sub>cc</sub> GND	dbx NR input for SAP signal
12	Reference	4.5V	12 V <sub>CC</sub> 50k Ω Θ GND	Stabilizing signal for reference power supply

Pin No.	Pin name	Pin voltage (V <sub>CC</sub> = 9V)	Equivalent circuit	Description
13	dbx timing current	1.2V	V <sub>cc</sub> 1.2V  1.5kΩ  GND	Control of the timing current for dbx r.m.s. value detection
14	Spectral level sensor input	4.7V	V <sub>cc</sub> 0.9kΩ  GND	Input for the r.m.s. value detection circuit for variable emphasis
15	Spectral timing	0.2V	V <sub>CC</sub> Θ 7.5 μA Θ 15 μA GND	Control of the r.m.s. value detection recovery-time for variable emphasis
16	Wide-band level sensor input	4.7V	V <sub>cc</sub> 0 4.7V  GND	Input for the r.m.s. value detection circuit for wide-band expander
17	Wide-band timing	0.2V	V <sub>cc</sub> Θ 7.5 μA Θ 15 μA GND	Control of the r.m.s. value detection recovery-time for wide-band expander
18	Spectral level adjustment	8.0V	V <sub>CC</sub> 20k Ω  50 μA GND	Control of the level of variable emphasis

Pin No.	Pin name	Pin voltage (V <sub>CC</sub> =9V)	Equivalent circuit	Description
19	Spectral CCA offset elimination	4.7V	V <sub>cc</sub> 19 29.5k Ω 29.5k Ω GND	To eliminate the DC offset for variable emphasis CCA
20	Wide-band level adjustment	8.0V	V <sub>cc</sub> 20kΩ  50 μA GND	To adjust the level of wide-band expander
21	Wide-band CCA offset elimination	4.7V	V <sub>cc</sub> 21  29.5kΩ  GND	To eliminate the DC offset for wideband expander CCA
22	Stereo LED		$V_{cc}$ $100k\Omega$ GND	To connect the stereo LED
23	Pilot signal detection	6.8V	$V_{cc}$ $V$	To detect the stereo pilot signal
24	LED GND	ov		GND pin for LED lighting circuit

Pin No.	Pin name	Pin voltage (V <sub>CC</sub> =9V)	Equivalent circuit	Description
25	GND	0V	·	Ground
26	Stereo VCO adjustment	7.8V	V <sub>cc</sub> 11.23kΩ  6 100 μA  GND	To adjust the stereo PLL-VCO oscillation frequency
27	Stereo PLL filter	4.7V	$V_{cc}$ $V$	To connect the stereo PLL low pass filter
28	Stereo demodulation input	4.7V	V <sub>cc</sub>   50kΩ   GND	Input pin of the stereo demodulation circuit
29	SAP noise level setting	3V	$V_{cc}$ $V$	To detect the noise of SAP-malfunction prevention-circuit  ( Mutes the SAP demodulation at noise detection
30	SAP noise level setting	3V	$V_{\rm CC}$ $\begin{array}{c} 30 \\ 3.5 \text{k} \Omega \end{array}$ $\begin{array}{c} 30 \text{k} \Omega \\ \end{array}$ $\begin{array}{c} \text{GND} \end{array}$	To set the noise level of SAP-malfunction prevention-circuit

Pin No	. Pin name	Pin voltage (V <sub>CC</sub> =9V)	Equivalent circuit	Description
31	SAP VCO adjustment	0.1V	V <sub>cc</sub>   550 Ω   500 Ω   GND	Fine adjustment of oscillation frequency of SAP-VCO (Normally, not used)
32	Vcc	9V		V <sub>CC</sub> pin
33	SAP-LED		V <sub>cc</sub> 100k Ω  GND	To a SAP-LED
34	SAP carrier detection	2V	$V_{\rm cc}$ $\begin{array}{cccccccccccccccccccccccccccccccccccc$	To detect the carrier level of SAP-signal
35	(L-R) demodulation output	4.0V	$V_{cc}$ $35$ $0$ $0$ $0$ $0$ $0$ $0$ $0$ $0$ $0$ $0$	(L-R) demodulation signal-output
36	SAP output detection	0V 9V at SAP ON 9V)	V <sub>cc</sub> 100kΩ GND	When SAP is output to the line-out, HIGH (9V) is output.

Pin No.	Pin name	Pin voltage (V <sub>CC</sub> =9V)	Equivalent circuit	Description
37	SAP demodulation output	3.5V	$V_{\rm cc}$ $\begin{array}{c} V_{\rm cc} \\ \hline 200\Omega \\ \hline 3k\Omega \\ \hline 12k\Omega \\ \hline \end{array}$	SAP-demodulation signal-output
38	Stereo filter output	4.0V	V <sub>cc</sub> V <sub>cc</sub> V <sub>cc</sub> GND	Stereo-filter output
39	Composite input	4.7V	$V_{cc}$ $V$	Composite-signal input
40	(L+R) demodulation output	4.0V	V <sub>cc</sub> 40  100 μA  GND	(L+R) demodulation-signal output
41	f <sub>H</sub> monitor output	4.3V L <sub>2.3V</sub> Stereo at LED ON	$V_{\rm cc}$	Stereo-PLL VCO-oscillation monitor
42	Quasi-sine wave filter	4.7V	$V_{cc}$ $V$	To a low-pass filter of the quasi-sine-wave circuit

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